/ Descriptions

TO-220 PNP Silicon PNP transistor in a TO-220 Plastic Package.

/ Features

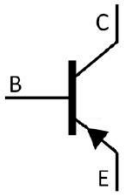
TIP31

Complement to TIP31.

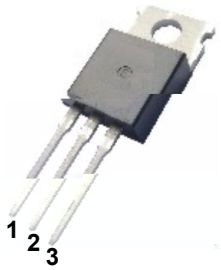
/ Applications

Medium power linear switching applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

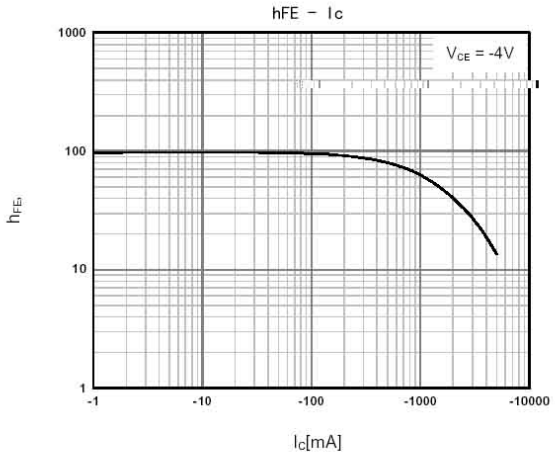
/ h_{FE} Classifications & Marking

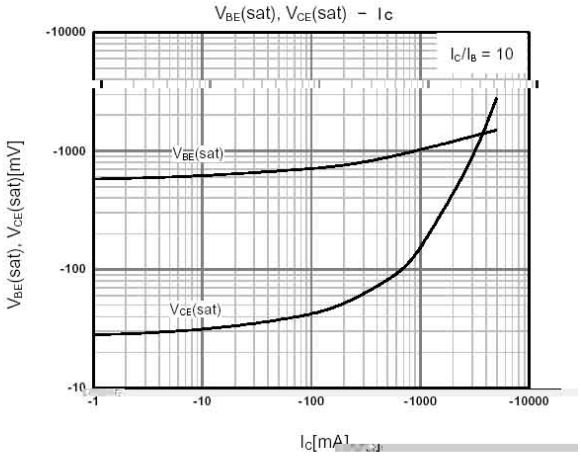
See Marking Instructions.

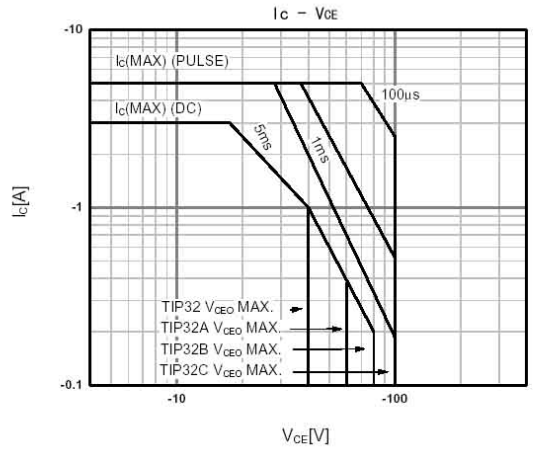
Parameter	Symbol	Rating				Unit
		TIP32	TIP32A	TIP32B	TIP32C	
Collector to Base Voltage	V_{CBO}	-40	-60	-80	-100	V
Collector to Emitter Voltage	V_{CEO}	-40	-60	-80	-100	V
Emitter to Base Voltage	V_{EBO}	-5.0				V
Collector Current-Continuous	I_C	-3.0				A
Peak Collector Current	I_{CP}	-5.0				A
Base Current - Continuous	I_B	-3.0				A
Collector Power Dissipation	P_C	2.0				W
Collector Power Dissipation	P_C (Tc=25℃)	40				W
Junction Temperature	T_j	150				℃
Storage Temperature Range	T_{sag}	-55～150				℃

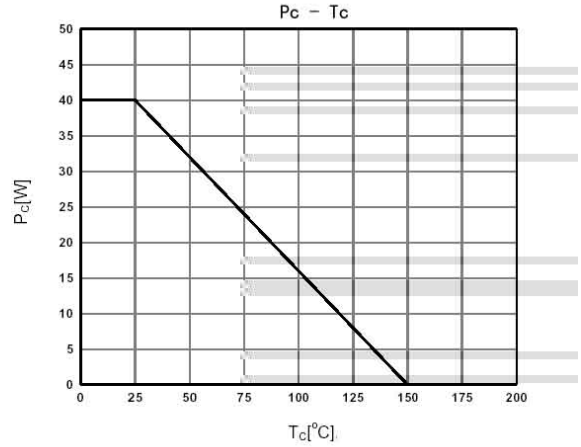
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unity1AH1A&1A6

/ Electrical Characteristic Curve



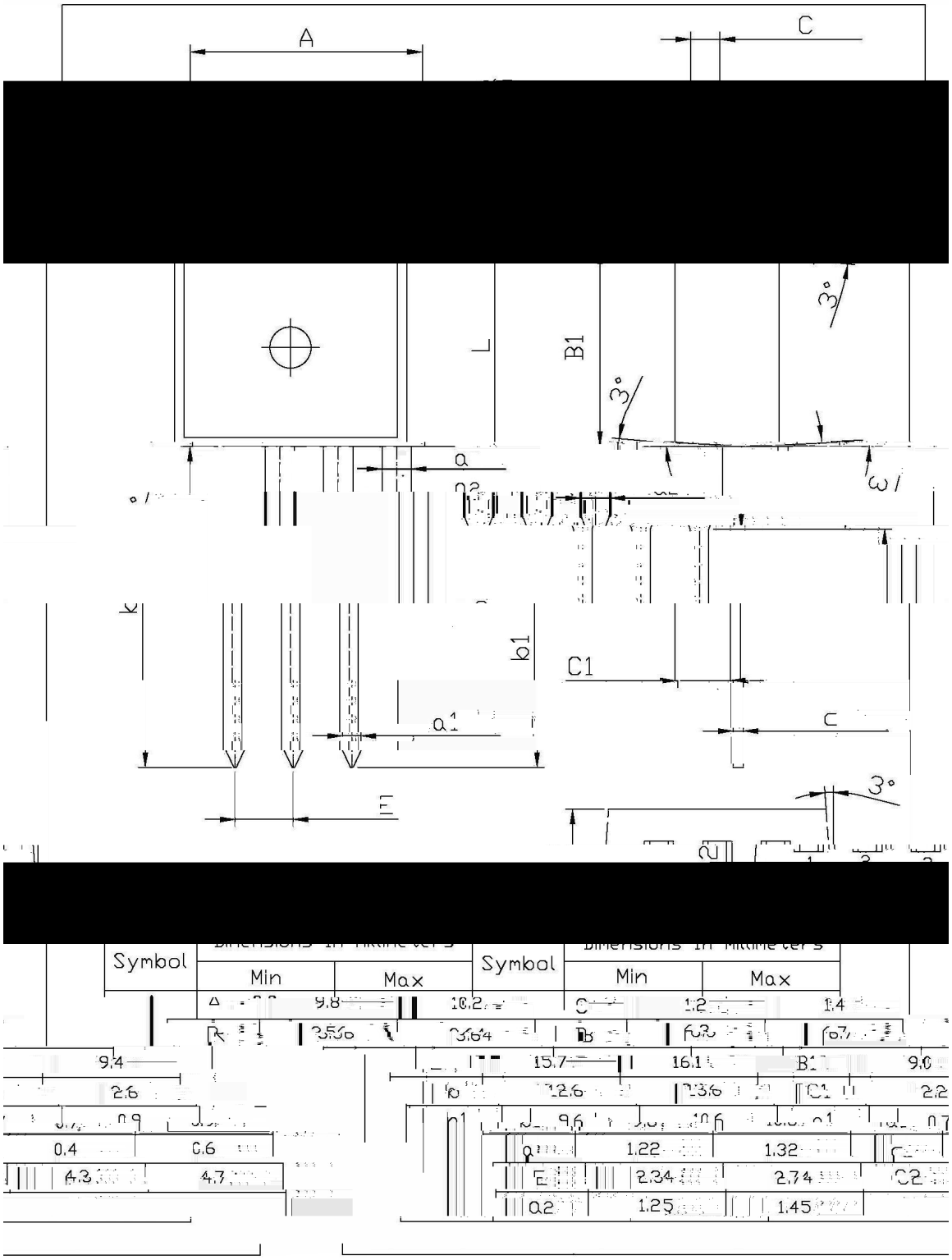




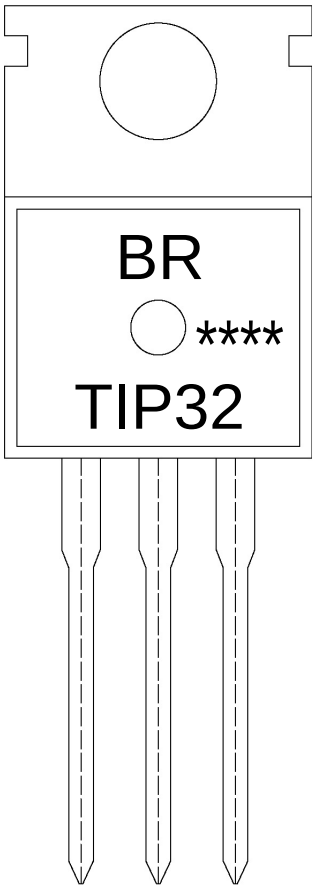


/ Package Dimensions

TO-220 单位：mm



/ Marking Instructions



BR

TIP32

****

Note:

BR:	Company Code
TIP32:	Product Type.
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)

				Note:
1	25 150	60	90sec;	1.Preheating:25~150 , Time:60~90sec.
2	255±5		5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3		2 10	/sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

270±5	10±1 sec.	Temp.:270±5℃	Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm^3)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Tube 套管	Inner Box 盒	Outer Box 箱
TO-220/F	50	20	1,000	5	5,000	532×31.4×5.5	555×164×50	575×290×180

/ Notices